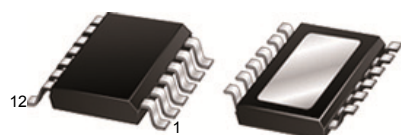


## Double channel high-side driver with analog current sense for 24 V automotive applications



PowerSSO-12

### Features

| Description                            | Parameter | Value               |
|----------------------------------------|-----------|---------------------|
| Max. transient supply voltage          | $V_{CC}$  | 58 V                |
| Operating voltage range                | $V_{CC}$  | 8 to 36 V           |
| Typ. on-state resistance (per channel) | $R_{ON}$  | 100 mΩ              |
| Current limitation (typ.)              | $I_{LIM}$ | 22 A                |
| Off-state supply current               | $I_S$     | 2 μA <sup>(1)</sup> |

1. Typical value with all loads connected.

- AEC-Q100 qualified 
- General
  - Very low standby current
  - 3.0 V CMOS compatible input
  - Optimized electromagnetic emission
  - Very low electromagnetic susceptibility
  - Compliant with European directive 2002/95/EC
  - Fault reset standby pin (FR\_Stby)
- Diagnostic functions
  - Proportional load current sense
  - High current sense precision for wide range currents
  - Off-state open-load detection
  - Output short to  $V_{CC}$  detection
  - Overload and short to ground latch-off
  - Thermal shutdown latch-off
  - Very low current sense leakage
- Protections
  - Undervoltage shutdown
  - Overvoltage clamp
  - Load current limitation
  - Self limiting of fast thermal transients
  - Protection against loss of ground and loss of  $V_{CC}$
  - Thermal shutdown
  - Electrostatic discharge protection

### Applications

- All types of resistive, inductive and capacitive loads

| Product status link          |
|------------------------------|
| <a href="#">VND5T100AJ-E</a> |

| Product summary |                |
|-----------------|----------------|
| Order code      | VND5T100AJTR-E |
| Package         | PowerSSO-12    |
| Packing         | Tape and reel  |

## Description

The VND5T100AJ-E is a monolithic device made using STMicroelectronics VIPower technology, intended for driving resistive or inductive loads with one side connected to the ground. Active  $V_{CC}$  pin voltage clamp protects the device against low energy spikes.

The device integrates an analog current sense, which delivers a current proportional to the load current.

Fault conditions such as overload, overtemperature, or short to  $V_{CC}$  are reported via the current sense pin.

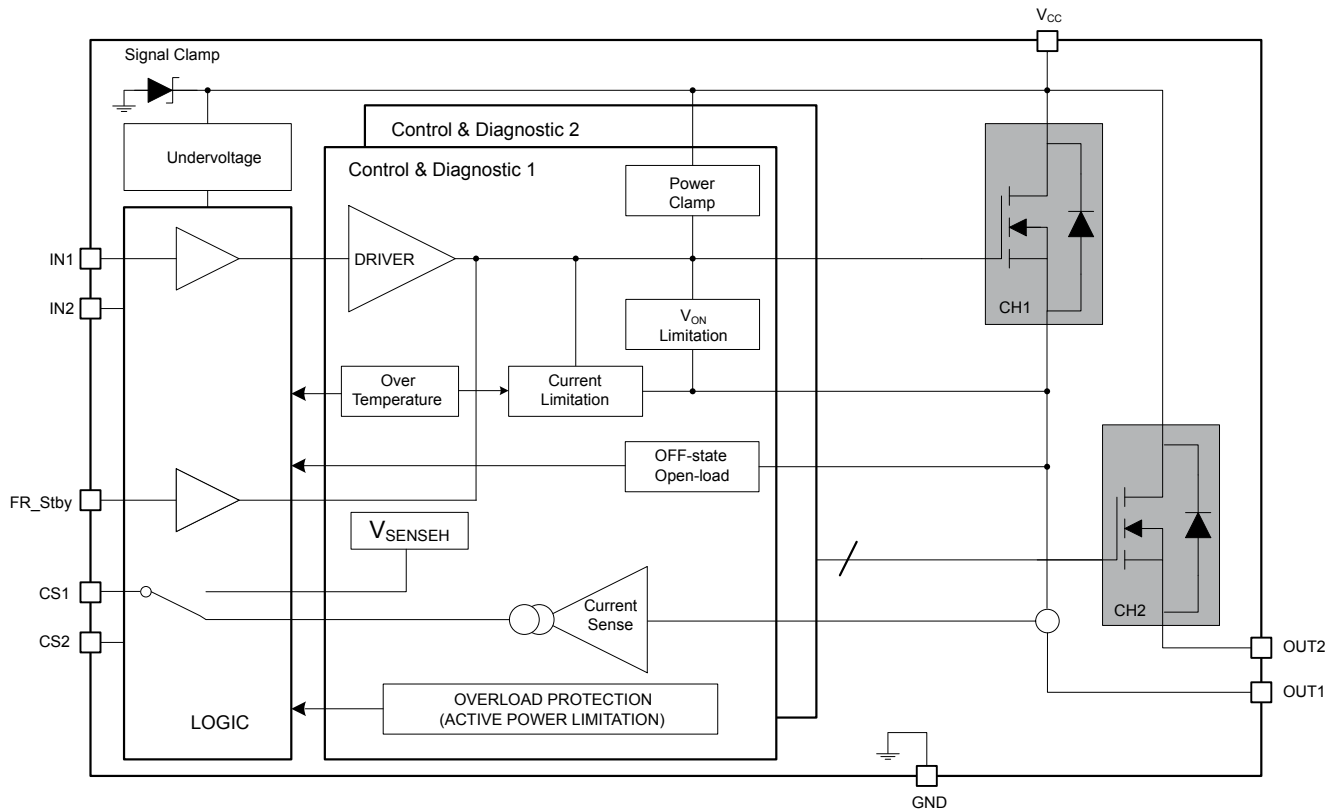
Output current limitation protects the device in overload conditions. The device latches off in case of overload or thermal shutdown.

The device is reset by a low level pass on the fault reset standby pin.

A permanent low level on the inputs and on the fault reset standby pins disables all outputs and sets the device in standby mode.

## 1 Block diagram and pin description

Figure 1. Block diagram

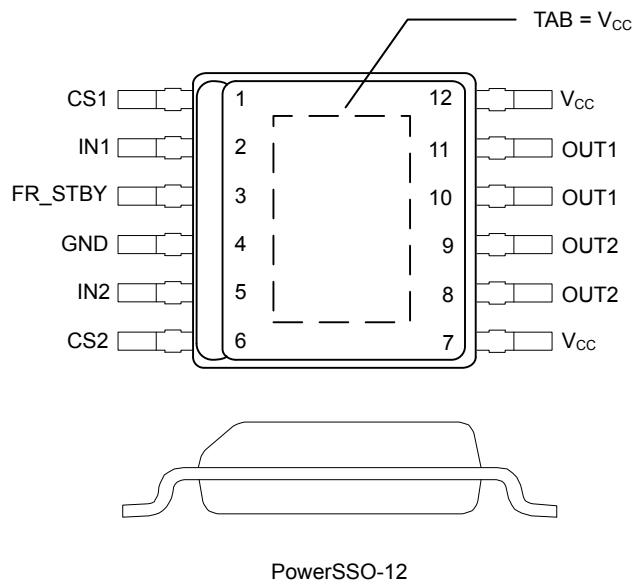


GAPGCFT00643

Table 1. Pin function

| Name     | Function                                                                                                                                                                                                       |
|----------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| $V_{CC}$ | Battery connection.                                                                                                                                                                                            |
| OUT1, 2  | Power outputs.                                                                                                                                                                                                 |
| GND      | Ground connection.                                                                                                                                                                                             |
| IN1, 2   | Voltage controlled input pins with hysteresis, CMOS compatible. They control output switch state.                                                                                                              |
| CS1, 2   | Analog current sense pins, they deliver a current proportional to the load current.                                                                                                                            |
| FR_Stby  | In case of latch-off for overtemperature/overcurrent condition, a low pulse on the FR_Stby pin is needed to reset the channel.<br>The device enters in standby mode if all inputs and the FR_Stby pin are low. |

**Figure 2. Configuration diagram PowerSSO-12 (top view)**



GAPGCFT000109

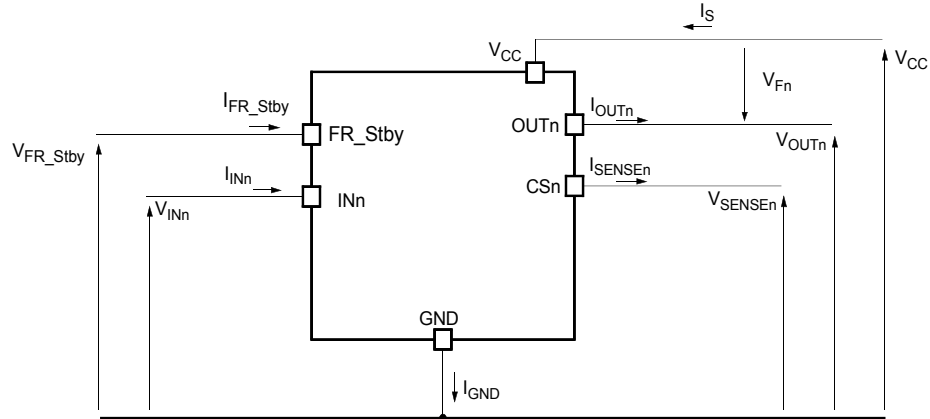
**Table 2. Suggested connections for unused and not connected pins**

| Connection/pin | CurrentSense           | NC               | Output      | Input                  | FR_Stby                |
|----------------|------------------------|------------------|-------------|------------------------|------------------------|
| Floating       | Not allowed            | X <sup>(1)</sup> | X           | X                      | X                      |
| To ground      | Through 10 kΩ resistor | X                | Not allowed | Through 10 kΩ resistor | Through 10 kΩ resistor |

1. X: do not care.

## 2 Electrical specification

**Figure 3. Current and voltage conventions**



GAPGCF00195\_v2

### 2.1 Absolute maximum ratings

Stressing the device above the ratings listed in the [Table 3](#) may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to the conditions reported in this section for extended periods may affect device reliability.

**Table 3. Absolute maximum ratings**

| Symbol         | Parameter                                                                                                                                   | Value                       | Unit |
|----------------|---------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------|------|
| $V_{CC}$       | DC supply voltage                                                                                                                           | 58                          | V    |
| $-V_{CC}$      | Reverse DC supply voltage                                                                                                                   | 0.3                         | V    |
| $-I_{GND}$     | DC reverse ground pin current                                                                                                               | 200                         | mA   |
| $I_{OUT}$      | DC output current                                                                                                                           | Internally limited          | A    |
| $-I_{OUT}$     | Reverse DC output current                                                                                                                   | 20                          | A    |
| $I_{IN}$       | DC input current                                                                                                                            | -1 to 10                    | mA   |
| $I_{FR\_Stby}$ | Fault reset standby DC input current                                                                                                        | -1 to 1.5                   | mA   |
| $-I_{CSENSE}$  | DC reverse CS pin current                                                                                                                   | 200                         | mA   |
| $V_{CSENSE}$   | Current sense maximum voltage                                                                                                               | $(V_{CC} - 58)$ to $V_{CC}$ | V    |
| $E_{MAX}$      | Maximum switching energy<br>( $L = 1.9$ mH; $V_{BAT} = 32$ V; $T_{Jstart} = 150$ °C; $I_{OUT} = I_{limL}$ (typ.))                           | 70                          | mJ   |
| $L_{smax}$     | Maximum stray inductance in short circuit condition<br>$R_L = 300$ mΩ, $V_{BAT} = 32$ V, $T_{Jstart} = 150$ °C, $I_{OUT} = I_{limH}$ (max.) | 40                          | μH   |
| $V_{ESD}$      | Electrostatic discharge (human body model: $R = 1.5$ kΩ, $C = 100$ pF)                                                                      | IN1, 2                      | 4000 |
|                |                                                                                                                                             | CS1, 2                      | 2000 |
|                |                                                                                                                                             | FR_Stby                     | 4000 |
|                |                                                                                                                                             | OUT1, 2                     | 5000 |
|                |                                                                                                                                             | $V_{CC}$                    | 5000 |
| $V_{ESD}$      | Charge device model (CDM-AEC-Q100-011)                                                                                                      | 750                         | V    |
| $T_J$          | Junction operating temperature                                                                                                              | -40 to 150                  | °C   |

| Symbol           | Parameter           | Value      | Unit |
|------------------|---------------------|------------|------|
| $T_{\text{stg}}$ | Storage temperature | -55 to 150 | °C   |

## 2.2 Thermal data

**Table 4. Thermal data**

| Symbol            | Parameter                                                  | Value                         | Unit |
|-------------------|------------------------------------------------------------|-------------------------------|------|
| $R_{\text{thJC}}$ | Thermal resistance, junction-to-case (with one channel ON) | 6                             | °C/W |
| $R_{\text{thJA}}$ | Thermal resistance, junction-to-ambient                    | See <a href="#">Figure 27</a> | °C/W |

## 2.3

### Electrical characteristics

8 V < V<sub>CC</sub> < 36 V, -40 °C < T<sub>J</sub> < 150 °C, unless otherwise specified.

**Table 5. Power section**

| Symbol               | Parameter                              | Test conditions                                                                                                                                            | Min. | Typ.             | Max.             | Unit |
|----------------------|----------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------------------|------------------|------|
| V <sub>CC</sub>      | Operating supply voltage               |                                                                                                                                                            | 8    | 24               | 36               | V    |
| V <sub>USD</sub>     | Undervoltage shutdown                  |                                                                                                                                                            |      | 3.5              | 5                | V    |
| V <sub>USDhyst</sub> | Undervoltage shutdown hysteresis       |                                                                                                                                                            |      | 0.5              |                  | V    |
| R <sub>ON</sub>      | On-state resistance <sup>(1)</sup>     | I <sub>OUT</sub> = 1.5 A, T <sub>J</sub> = 25 °C                                                                                                           |      | 100              |                  | mΩ   |
|                      |                                        | I <sub>OUT</sub> = 1.5 A, T <sub>J</sub> = 150 °C                                                                                                          |      |                  | 200              |      |
| V <sub>clamp</sub>   | Clamp voltage                          | I <sub>S</sub> = 20 mA                                                                                                                                     | 58   | 64               | 70               | V    |
| I <sub>S</sub>       | Supply current                         | Off-state, V <sub>CC</sub> = 24 V, T <sub>J</sub> = 25 °C,<br>V <sub>IN</sub> = V <sub>OUT</sub> = V <sub>SENSE</sub> = 0 V,<br>V <sub>FR_Stby</sub> = 0 V |      | 2 <sup>(2)</sup> | 5 <sup>(2)</sup> | μA   |
|                      |                                        | On-state, V <sub>CC</sub> = 24 V,<br>V <sub>IN</sub> = 5 V, I <sub>OUT</sub> = 0 A                                                                         |      | 4.2              | 6                | mA   |
| I <sub>L(off)</sub>  | Off-state output current               | V <sub>IN</sub> = V <sub>OUT</sub> = 0 V,<br>V <sub>CC</sub> = 24 V, T <sub>J</sub> = 25 °C                                                                | 0    | 0.01             | 3                | μA   |
|                      |                                        | V <sub>IN</sub> = V <sub>OUT</sub> = 0 V,<br>V <sub>CC</sub> = 24 V, T <sub>J</sub> = 125 °C                                                               | 0    |                  | 5                |      |
| V <sub>F</sub>       | Output - V <sub>CC</sub> diode voltage | -I <sub>OUT</sub> = 1.5 A, T <sub>J</sub> = 150 °C                                                                                                         |      |                  | 0.7              | V    |

1. For each channel.

2. Power MOSFET leakage included.

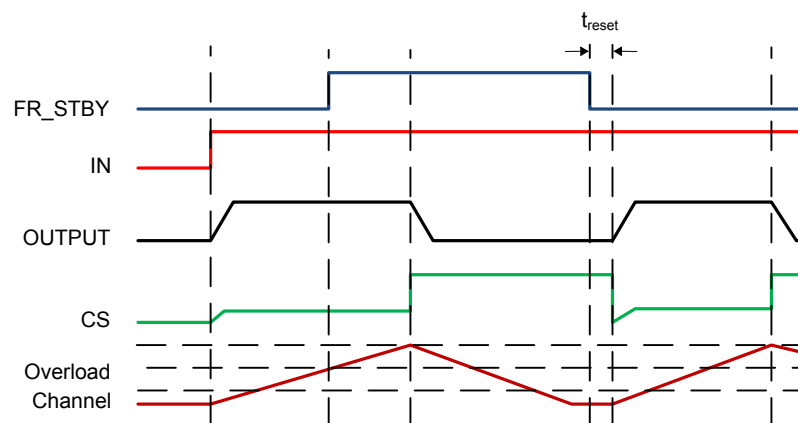
**Table 6. Switching (V<sub>CC</sub> = 24 V, T<sub>J</sub> = 25 °C)**

| Symbol                                   | Parameter                                        | Test conditions       | Min. | Typ. | Max. | Unit |
|------------------------------------------|--------------------------------------------------|-----------------------|------|------|------|------|
| t <sub>d(on)</sub>                       | Turn-on delay time                               | R <sub>L</sub> = 16 Ω |      | 27   |      | μs   |
| t <sub>d(off)</sub>                      | Turn-off delay time                              | R <sub>L</sub> = 16 Ω |      | 38   |      | μs   |
| (dV <sub>OUT</sub> /dt) <sub>(on)</sub>  | Turn-on voltage slope                            | R <sub>L</sub> = 16 Ω |      | 1    |      | V/μs |
| (dV <sub>OUT</sub> /dt) <sub>(off)</sub> | Turn-off voltage slope                           | R <sub>L</sub> = 16 Ω |      | 0.65 |      | V/μs |
| W <sub>ON</sub>                          | Switching energy losses during t <sub>won</sub>  | R <sub>L</sub> = 16 Ω |      | 0.23 |      | mJ   |
| W <sub>OFF</sub>                         | Switching energy losses during t <sub>woff</sub> | R <sub>L</sub> = 16 Ω |      | 0.26 |      | mJ   |

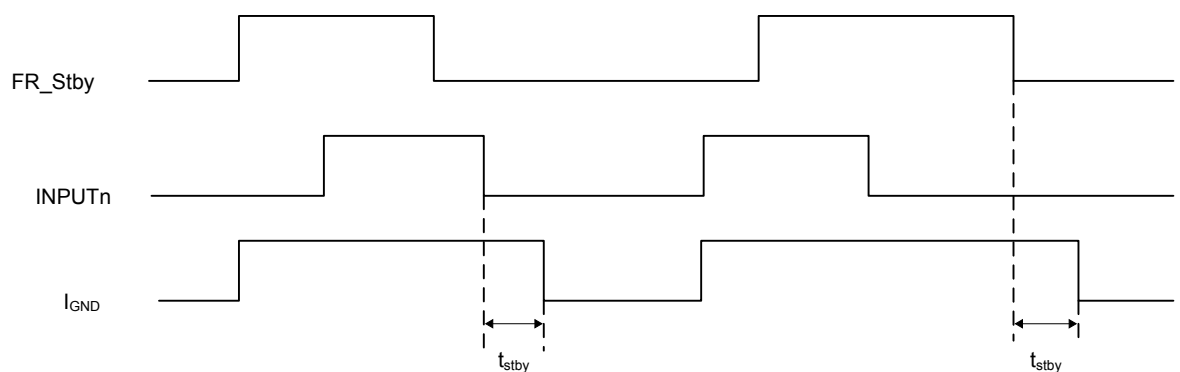
**Table 7. Logic inputs**

| Symbol               | Parameter                | Test conditions         | Min. | Typ. | Max. | Unit |
|----------------------|--------------------------|-------------------------|------|------|------|------|
| V <sub>IL</sub>      | Input low level voltage  |                         |      |      | 0.9  | V    |
| I <sub>IL</sub>      | Low level input current  | V <sub>IN</sub> = 0.9 V | 1    |      |      | μA   |
| V <sub>IH</sub>      | Input high level voltage |                         | 2.1  |      |      | V    |
| I <sub>IH</sub>      | High level input current | V <sub>IN</sub> = 2.1 V |      |      | 10   | μA   |
| V <sub>I(hyst)</sub> | Input hysteresis voltage |                         | 0.25 |      |      | V    |

| Symbol               | Parameter                              | Test conditions                                     | Min. | Typ. | Max. | Unit          |
|----------------------|----------------------------------------|-----------------------------------------------------|------|------|------|---------------|
| $V_{ICL}$            | Input clamp voltage                    | $I_{IN} = 1 \text{ mA}$                             | 5.5  |      | 7    | V             |
|                      |                                        | $I_{IN} = -1 \text{ mA}$                            |      | -0.7 |      |               |
| $V_{FR\_Stby\_L}$    | Fault_reset_standby low level voltage  |                                                     |      |      | 0.9  | V             |
| $I_{FR\_Stby\_L}$    | Low level fault_reset_standby current  | $V_{FR\_Stby} = 0.9 \text{ V}$                      | 1    |      |      | $\mu\text{A}$ |
| $V_{FR\_Stby\_H}$    | Fault_reset_standby high level voltage |                                                     | 2.1  |      |      | V             |
| $I_{FR\_Stby\_H}$    | High level fault_reset_standby current | $V_{FR\_Stby} = 2.1 \text{ V}$                      |      |      | 10   | $\mu\text{A}$ |
| $V_{FR\_Stby(hyst)}$ | Fault_reset_standby hysteresis voltage |                                                     | 0.25 |      |      | V             |
| $V_{FR\_Stby\_CL}$   | Fault_reset_standby clamp voltage      | $I_{FR\_Stby} = 15 \text{ mA (} t < 10 \text{ ms)}$ | 11   |      | 15   | V             |
|                      |                                        | $I_{FR\_Stby} = -1 \text{ mA}$                      |      | -0.7 |      | V             |
| $t_{reset}$          | Overload latch-off reset time          | See Figure 4                                        | 2    |      | 24   | $\mu\text{s}$ |
| $t_{stby}$           | Standby delay                          | See Figure 5                                        | 120  |      | 1200 | $\mu\text{s}$ |

**Figure 4.  $t_{reset}$  definition**


GAPGCFT000112

**Figure 5.  $t_{stby}$  definition**


GAPGCFT000111\_v2

**Table 8. Protections and diagnostics**

| Symbol      | Parameter                                    | Test conditions                                                | Min.          | Typ.          | Max.          | Unit |
|-------------|----------------------------------------------|----------------------------------------------------------------|---------------|---------------|---------------|------|
| $I_{limH}$  | DC short circuit current                     | $V_{CC} = 24\text{ V}$                                         | 16            | 22            | 30            | A    |
|             |                                              | $5\text{ V} < V_{CC} < 36\text{ V}$                            |               |               | 30            |      |
| $I_{limL}$  | Short circuit current during thermal cycling | $V_{CC} = 24\text{ V}, T_R < T_J < T_{TSD}$                    |               | 6             |               | A    |
| $T_{TSD}$   | Shutdown temperature                         |                                                                | 150           | 175           | 200           | °C   |
| $T_R$       | Reset temperature                            |                                                                | $T_{RS} + 1$  | $T_{RS} + 5$  |               | °C   |
| $T_{RS}$    | Thermal reset of status                      |                                                                | 135           |               |               | °C   |
| $T_{HYST}$  | Thermal hysteresis ( $T_{TSD} - T_R$ )       |                                                                |               | 7             |               | °C   |
| $V_{DEMAG}$ | Turn-off output voltage clamp                | $I_{OUT} = 1.5\text{ A}, V_{IN} = 0\text{ V}, L = 6\text{ mH}$ | $V_{CC} - 58$ | $V_{CC} - 64$ | $V_{CC} - 70$ | V    |
| $V_{ON}$    | Output voltage drop limitation               | $I_{OUT} = 50\text{ mA}, T_J = -40\text{ °C to }150\text{ °C}$ |               | 25            |               | mV   |

**Table 9. Current sense ( $8\text{ V} < V_{CC} < 36\text{ V}$ )**

| Symbol           | Parameter                        | Test conditions                                                                                           | Min. | Typ. | Max. | Unit          |
|------------------|----------------------------------|-----------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $K_1$            | $I_{OUT}/I_{SENSE}$              | $I_{OUT} = 350\text{ mA}, V_{SENSE} = 1\text{ V}, T_J = -40\text{ °C to }150\text{ °C}$                   | 930  | 1547 | 2185 |               |
|                  |                                  | $I_{OUT} = 350\text{ mA}, V_{SENSE} = 1\text{ V}, T_J = 25\text{ °C to }150\text{ °C}$                    | 1050 |      | 2020 |               |
| $dK_1/K_1^{(1)}$ | Current sense ratio drift        | $I_{OUT} = 350\text{ mA}, V_{SENSE} = 1\text{ V}, T_J = -40\text{ °C to }150\text{ °C}$                   | -15  |      | 15   | %             |
| $K_2$            | $I_{OUT}/I_{SENSE}$              | $I_{OUT} = 0.8\text{ A}, V_{SENSE} = 2\text{ V}, T_J = -40\text{ °C to }150\text{ °C}$                    | 1225 | 1528 | 1835 |               |
|                  |                                  | $I_{OUT} = 0.8\text{ A}, V_{SENSE} = 2\text{ V}, T_J = 25\text{ °C to }150\text{ °C}$                     | 1310 |      | 1745 |               |
| $dK_2/K_2^{(1)}$ | Current sense ratio drift        | $I_{OUT} = 0.8\text{ A}, V_{SENSE} = 2\text{ V}, T_J = -40\text{ °C to }150\text{ °C}$                    | -12  |      | 12   | %             |
| $K_3$            | $I_{OUT}/I_{SENSE}$              | $I_{OUT} = 1.5\text{ A}, V_{SENSE} = 2\text{ V}, T_J = -40\text{ °C to }150\text{ °C}$                    | 1340 | 1525 | 1715 |               |
|                  |                                  | $I_{OUT} = 1.5\text{ A}, V_{SENSE} = 2\text{ V}, T_J = 25\text{ °C to }150\text{ °C}$                     | 1405 |      | 1655 |               |
| $dK_3/K_3^{(1)}$ | Current sense ratio drift        | $I_{OUT} = 1.5\text{ A}, V_{SENSE} = 2\text{ V}, T_J = -40\text{ °C to }150\text{ °C}$                    | -8   |      | 8    | %             |
| $K_4$            | $I_{OUT}/I_{SENSE}$              | $I_{OUT} = 6\text{ A}, V_{SENSE} = 4\text{ V}, T_J = -40\text{ °C to }150\text{ °C}$                      | 1450 | 1522 | 1600 |               |
|                  |                                  | $I_{OUT} = 6\text{ A}, V_{SENSE} = 4\text{ V}, T_J = 25\text{ °C to }150\text{ °C}$                       | 1475 |      | 1560 |               |
| $dK_4/K_4^{(1)}$ | Current sense ratio drift        | $I_{OUT} = 6\text{ A}, V_{SENSE} = 4\text{ V}, T_J = -40\text{ °C to }150\text{ °C}$                      | -5   |      | 5    | %             |
| $I_{SENSE0}$     | Analog sense leakage current     | $I_{OUT} = 0\text{ A}, V_{SENSE} = 0\text{ V}, V_{IN} = 0\text{ V}, T_J = -40\text{ °C to }150\text{ °C}$ | 0    |      | 1    | $\mu\text{A}$ |
|                  |                                  | $I_{OUT} = 0\text{ A}, V_{SENSE} = 0\text{ V}, V_{IN} = 5\text{ V}, T_J = -40\text{ °C to }150\text{ °C}$ | 0    |      | 2    |               |
| $V_{SENSE}$      | Max. analog sense output voltage | $I_{OUT} = 6\text{ A}, R_{SENSE} = 3.9\text{ k}\Omega$                                                    | 5    |      |      | V             |

| Symbol                | Parameter                                                                                  | Test conditions                                                                                                                                              | Min. | Typ. | Max. | Unit          |
|-----------------------|--------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $V_{SENSEH}$          | Analog sense output voltage in fault condition <sup>(2)</sup>                              | $V_{CC} = 24\text{ V}$ , $R_{SENSE} = 3.9\text{ k}\Omega$                                                                                                    | 7.5  | 8.5  | 9.5  | V             |
| $I_{SENSEH}$          | Analog sense output current in fault condition <sup>(2)</sup>                              | $V_{CC} = 24\text{ V}$ , $V_{SENSE} = 5\text{ V}$                                                                                                            | 4.9  | 9    | 12   | mA            |
| $t_{DSENSE2H}$        | Delay response time from rising edge of INPUT pins                                         | $V_{SENSE} < 4\text{ V}$ , $0.07\text{ A} < I_{OUT} < 1.5\text{ A}$ ,<br>$I_{SENSE} = 90\%$ of $I_{SENSEMAX}$ ,<br>(see Figure 6)                            |      | 100  | 200  | $\mu\text{s}$ |
| $\Delta t_{DSENSE2H}$ | Delay response time between rising edge of output current and rising edge of current sense | $V_{SENSE} < 4\text{ V}$ ,<br>$I_{SENSE} = 90\%$ of $I_{SENSEMAX}$ ,<br>$I_{OUT} = 90\%$ of $I_{OUTMAX}$ ,<br>$I_{OUTMAX} = 1.5\text{ A}$<br>(see Figure 10) |      |      | 150  | $\mu\text{s}$ |
| $t_{DSENSE2L}$        | Delay response time from falling edge of INPUT pins                                        | $V_{SENSE} < 4\text{ V}$ ,<br>$0.07\text{ A} < I_{OUT} < 1.5\text{ A}$ ,<br>$I_{SENSE} = 10\%$ of $I_{SENSEMAX}$<br>(see Figure 6)                           |      | 5    | 20   | $\mu\text{s}$ |

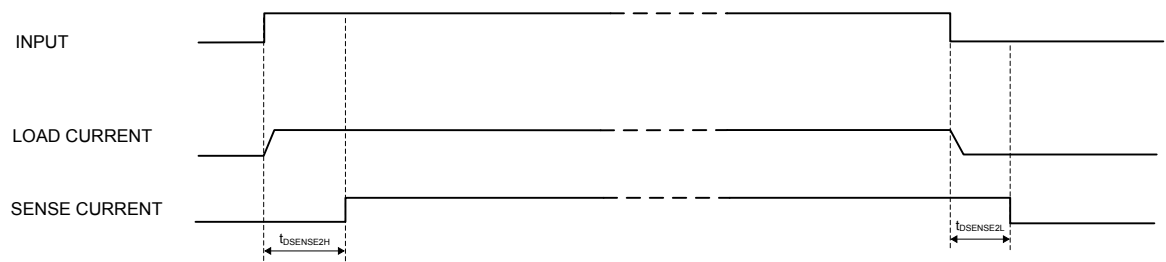
1. Specified by design, not tested in production.

2. Fault condition includes: power limitation, overtemperature and open-load in off-state condition.

**Table 10. Open-load detection ( $V_{FR\_Stby} = 5\text{ V}$ )**

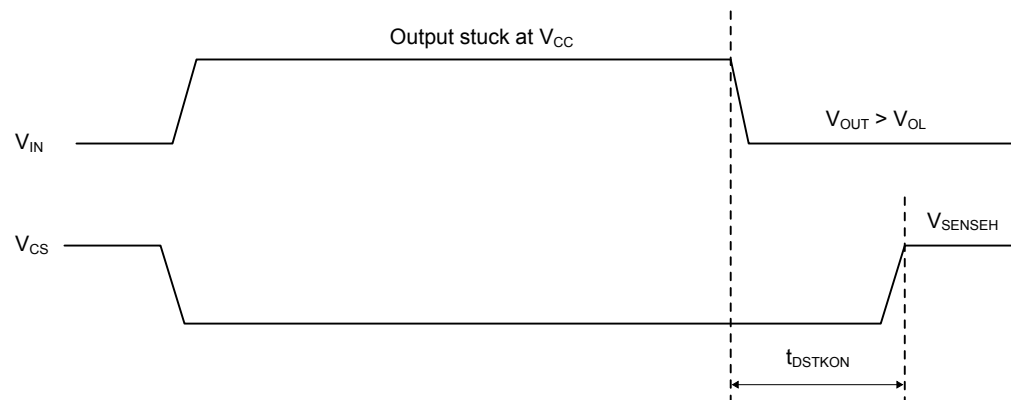
| Symbol           | Parameter                                                                      | Test conditions                                                                                                                                               | Min. | Typ. | Max. | Unit          |
|------------------|--------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $V_{OL}$         | Open-load off-state voltage detection threshold                                | $V_{IN} = 0\text{ V}$ , $8\text{ V} < V_{CC} < 36\text{ V}$ ,<br>$V_{FR\_Stby} = 5\text{ V}$                                                                  | 2    | -    | 4    | V             |
| $t_{DSTKON}$     | Output short circuit to $V_{CC}$ detection delay at turn off                   | $V_{FR\_Stby} = 5\text{ V}$<br>(see Figure 7)                                                                                                                 | 180  | -    | 1800 | $\mu\text{s}$ |
| $I_{L(off2)}$    | Off-state output current at $V_{OUT} = 4\text{ V}$                             | $V_{IN} = 0\text{ V}$ , $V_{SENSE} = 0\text{ V}$ ,<br>$V_{OUT}$ rising from $0\text{ V}$ to $4\text{ V}$ ,<br>$V_{FR\_Stby} = 5\text{ V}$                     | -120 | -    | 0    | $\mu\text{A}$ |
| $t_{d\_vol}$     | Delay response from output rising edge to $V_{SENSE}$ rising edge in open-load | $V_{OUT} = 4\text{ V}$ , $V_{IN} = 0\text{ V}$ ,<br>$V_{SENSE} = 90\%$ of $V_{SENSEH}$ ,<br>$R_{SENSE} = 3.9\text{ k}\Omega$ ,<br>$V_{FR\_Stby} = 5\text{ V}$ |      | -    | 20   | $\mu\text{s}$ |
| $t_{DFRSTK\_ON}$ | Output short circuit to $V_{CC}$ detection delay at $FR\_Stby$ activation      | Input1, 2 = low<br>(see Figure 9)                                                                                                                             |      | -    | 50   | $\mu\text{s}$ |

**Figure 6. Current sense delay characteristics**



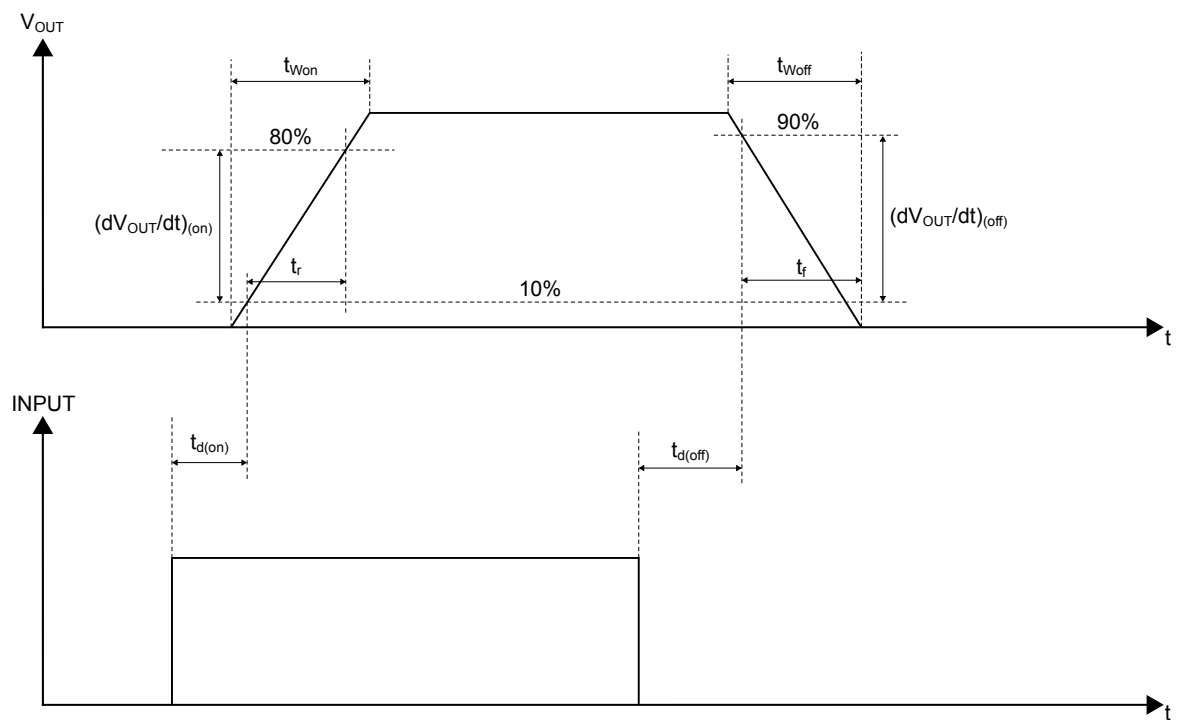
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**Figure 7. Open-load off-state delay timing**



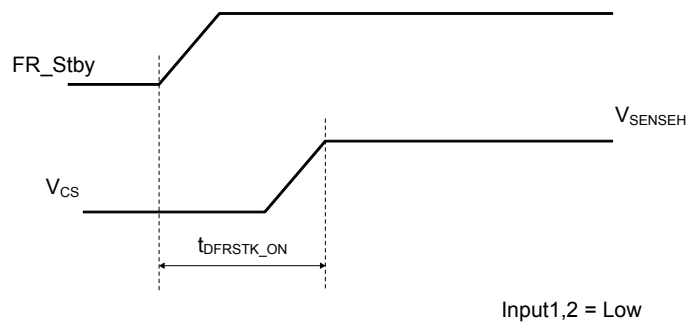
GAPGCFT000113

**Figure 8. Switching characteristics**



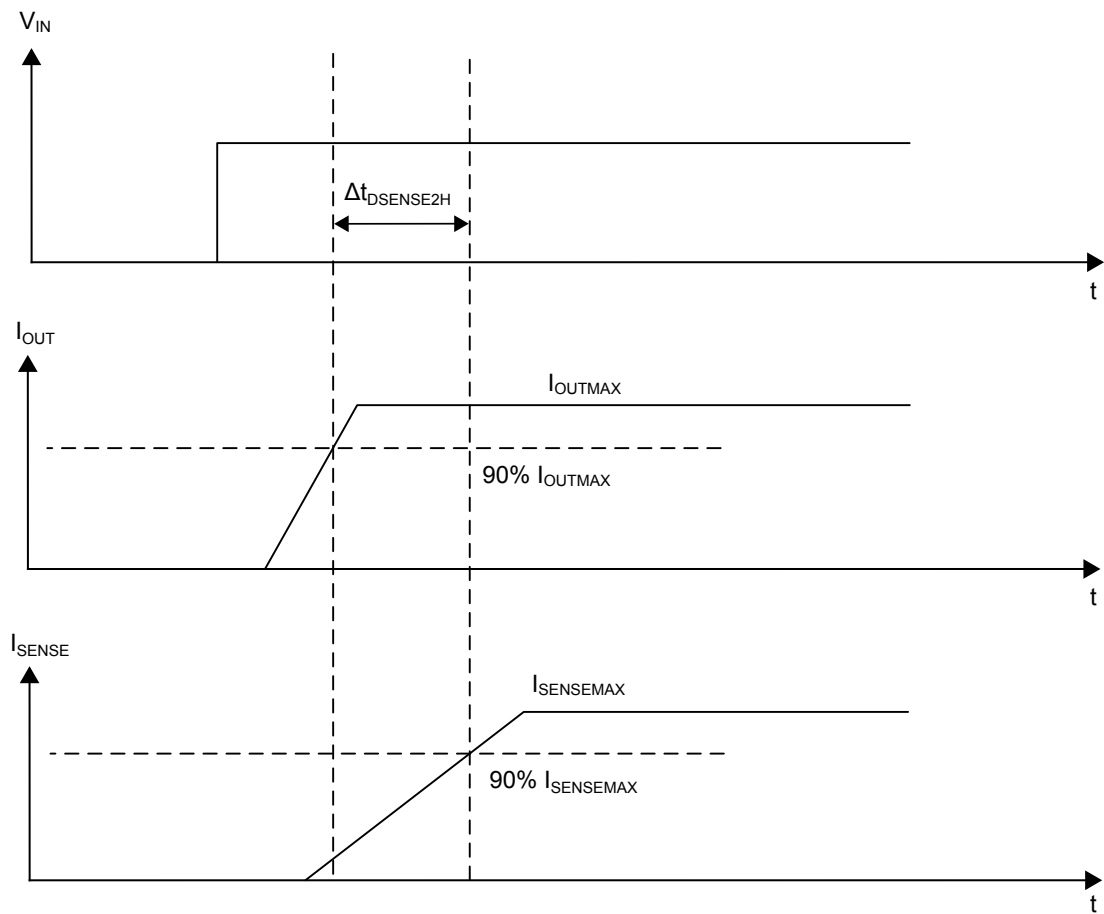
GAPGCFT000114

**Figure 9. Output stuck to  $V_{CC}$  detection delay time at FR\_Stby activation**



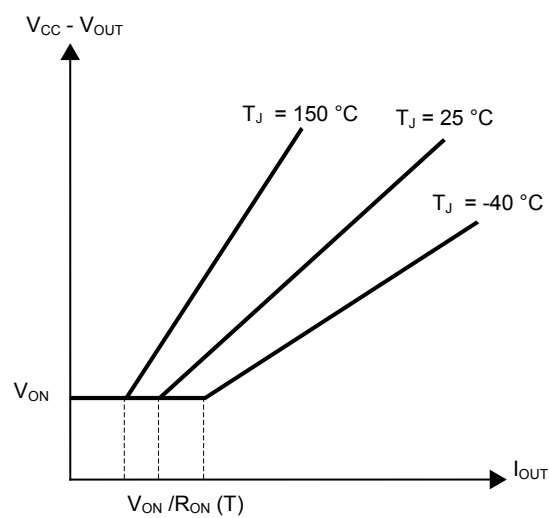
GAPGCFT00038\_v2

Figure 10. Delay response time between rising edge of output current and rising edge of current sense

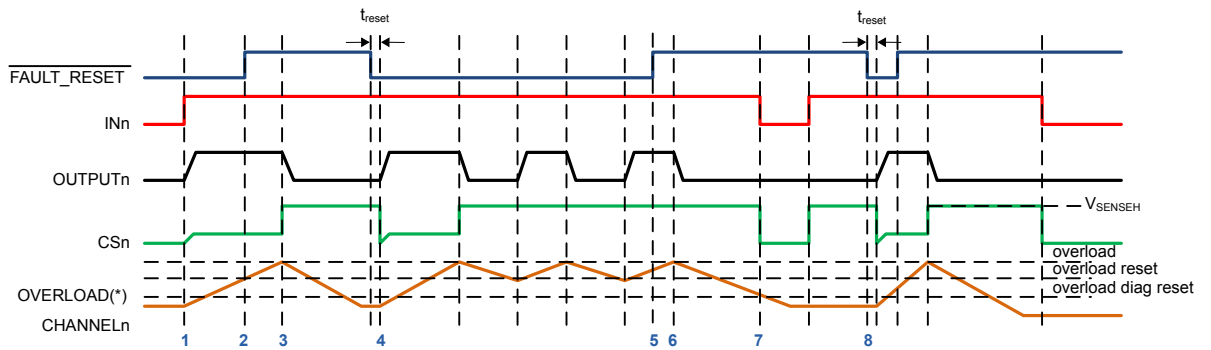


GAPGCFT000115

Figure 11. Output voltage drop limitation



AG00074V1

**Figure 12. Device behavior in overload condition**


- 1: OUTPUTn and CSn controlled by INn
- 2: FAULT\_RESET from '0' to '1' → no action on CSn pin
- 3: overload latch-off. INn high → CSn high
- 4: FAULT\_RESET low AND Temp channeln < overload\_reset → overload latch reset after t\_reset
- 4 to 5: FAULT\_RESET low AND INn high → thermal cycling, CSn high
- 5: FAULT\_RESET high → latch-off reset disabled
- 6 to 7: overload event and FAULT\_RESET high → latch-off, no thermal cycling
- 7 to 8: overload diagnostic disabled/enabled by the input
- 8: overload latch-off reset by FAULT\_RESET

(\*) OVERLOAD = thermal shutdown OR power limitation

GAPGCF000116\_v2

**Table 11. Truth table**

| Conditions                         | Fault reset standby | Input | Output   | Sense               |
|------------------------------------|---------------------|-------|----------|---------------------|
| Standby                            | L                   | L     | L        | 0                   |
| Normal operation                   | X                   | L     | L        | 0                   |
|                                    | X                   | H     | H        | Nominal             |
| Overload                           | X                   | L     | L        | 0                   |
|                                    | X                   | H     | H        | > Nominal           |
| Overtemperature/short to ground    | X                   | L     | L        | 0                   |
|                                    | L                   | H     | Cycling  | V <sub>SENSEH</sub> |
|                                    | H                   | H     | Latched  | V <sub>SENSEH</sub> |
| Undervoltage                       | X                   | X     | L        | 0                   |
| Short to V <sub>BAT</sub>          | L                   | L     | H        | 0                   |
|                                    | H                   | L     | H        | V <sub>SENSEH</sub> |
|                                    | X                   | H     | H        | < Nominal           |
| Open-load off-state (with pull-up) | L                   | L     | H        | 0                   |
|                                    | H                   | L     | H        | V <sub>SENSEH</sub> |
|                                    | X                   | H     | H        | 0                   |
| Negative output voltage clamp      | X                   | L     | Negative | 0                   |

**Table 12. Electrical transient requirements (part 1)**

| ISO 7637-2:<br>2004 (E)<br>Test pulse | Test levels <sup>(1)</sup> |         | Number of<br>pulses or<br>test times | Burst cycle/pulse<br>repetition time |        | Delays and<br>impedence |
|---------------------------------------|----------------------------|---------|--------------------------------------|--------------------------------------|--------|-------------------------|
|                                       | III                        | IV      |                                      |                                      |        |                         |
| 1                                     | -450 V                     | -600 V  | 5000<br>pulses                       | 0.5 s                                | 5 s    | 1 ms, 50 Ω              |
| 2a                                    | 37 V                       | 50 V    | 5000<br>pulses                       | 0.2 s                                | 5 s    | 50 μs, 2 Ω              |
| 3a                                    | - 150 V                    | - 200 V | 1 h                                  | 90 ms                                | 100 ms | 0.1 μs, 50 Ω            |
| 3b                                    | + 150 V                    | + 200 V | 1 h                                  | 90 ms                                | 100 ms | 0.1 μs, 50 Ω            |
| 4                                     | - 12 V                     | - 16 V  | 1 pulse                              |                                      |        | 100 ms, 0.01 Ω          |
| 5b <sup>(2)</sup>                     | + 123 V                    | + 174 V | 1 pulse                              |                                      |        | 350 ms, 1 Ω             |

1. The above test levels must be considered referred to  $V_{CC} = 24.5$  V except for pulse 5b.
2. Valid in case of external load dump clamp: 58 V maximum referred to ground.

**Table 13. Electrical transient requirements (part 2)**

| ISO 7637-2: 2004 (E)<br>Test pulse | Test level results |    |
|------------------------------------|--------------------|----|
|                                    | III                | IV |
| 1                                  | C                  | C  |
| 2a                                 | C                  | C  |
| 3a                                 | C                  | C  |
| 3b <sup>(1)</sup>                  | E                  | E  |
| 3b <sup>(2)</sup>                  | C                  | C  |
| 4                                  | C                  | C  |
| 5b <sup>(3)</sup>                  | C                  | C  |

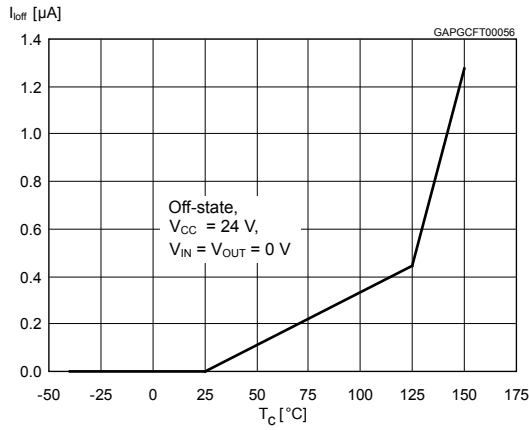
1. Without capacitor between  $V_{CC}$  and GND.
2. With 10 nF between  $V_{CC}$  and GND.
3. External load dump clamp, 58 V maximum, referred to ground.

**Table 14. Electrical transient requirements (part 3)**

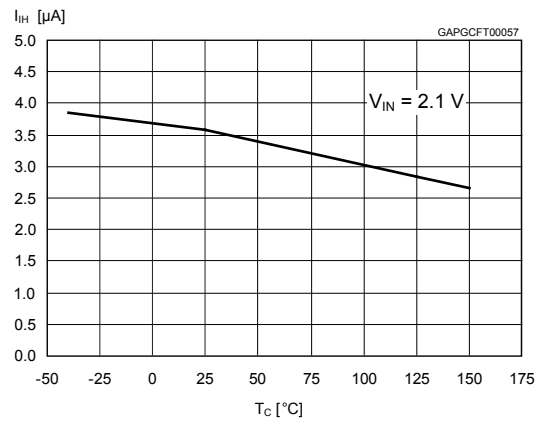
| Class | Contents                                                                                                                                                                 |
|-------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| C     | All functions of the device are performed as designed after exposure to disturbance.                                                                                     |
| E     | One or more functions of the device are not performed as designed after exposure to disturbance and cannot be returned to proper operation without replacing the device. |

## 2.4 Electrical characteristics (curves)

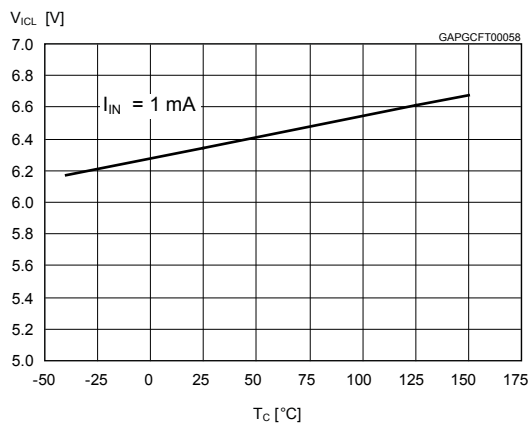
**Figure 13. Off-state output current**



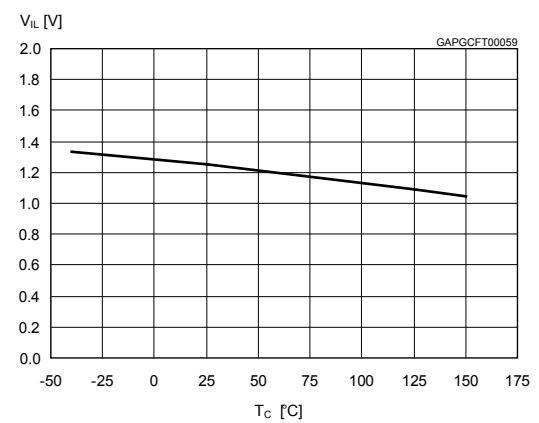
**Figure 14. High level input current**



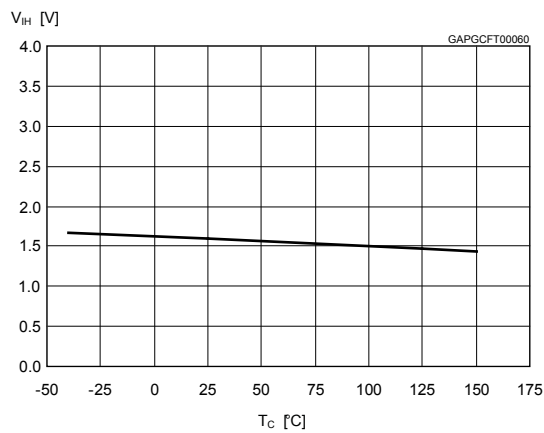
**Figure 15. Input clamp voltage**



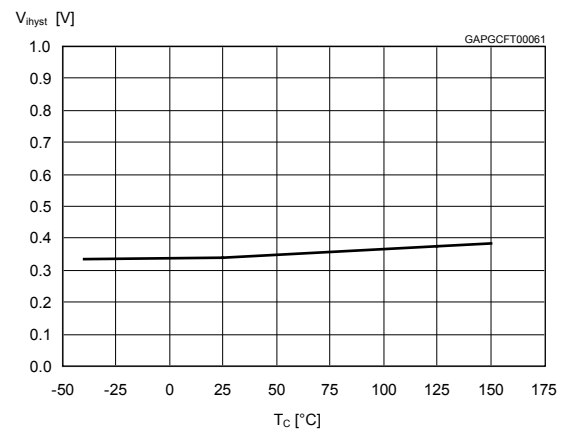
**Figure 16. Low level input voltage**

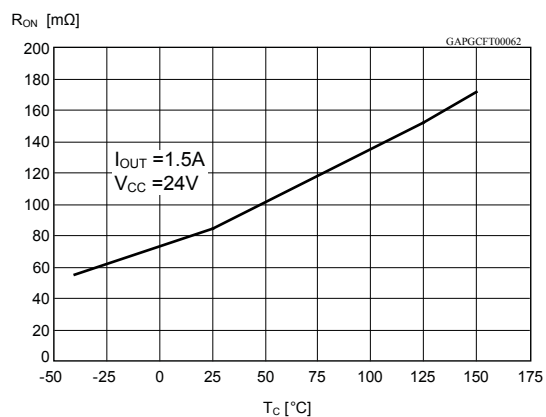
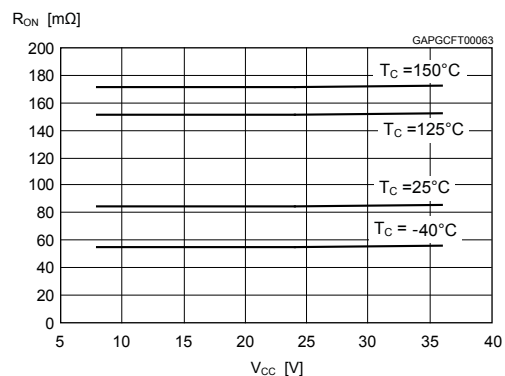
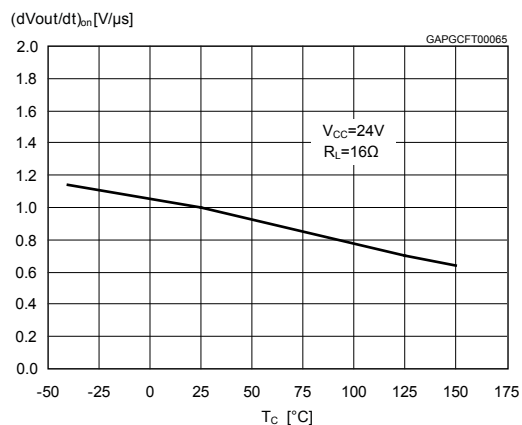
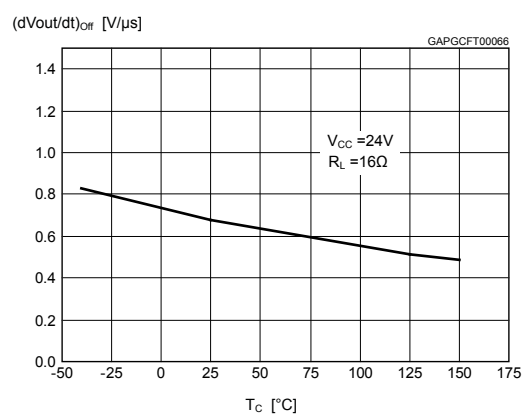
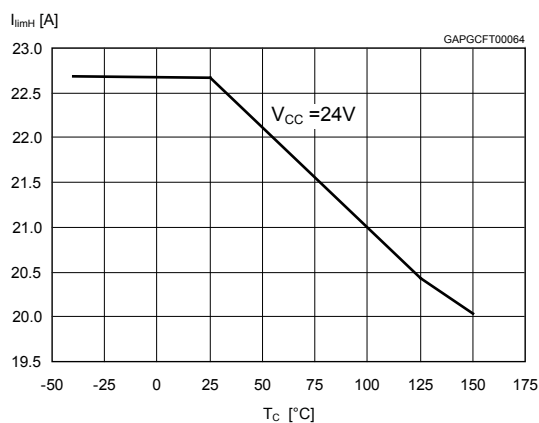


**Figure 17. High level input voltage**



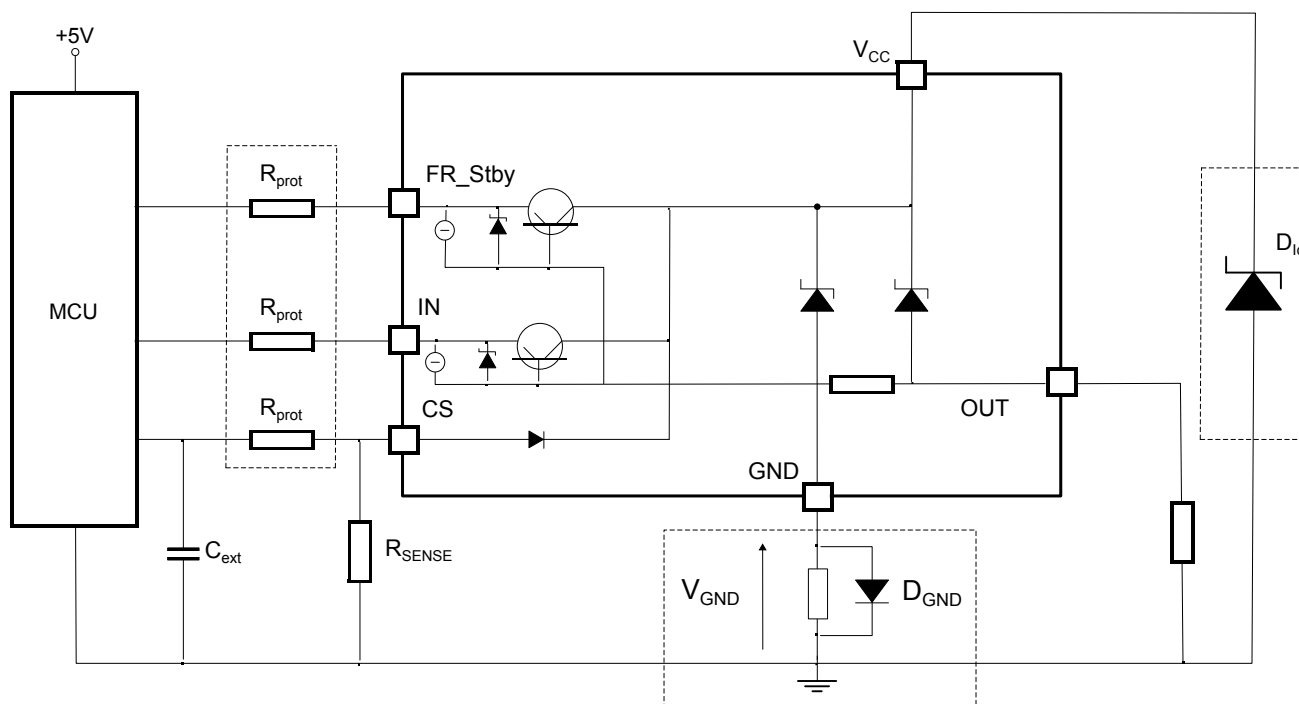
**Figure 18. Input hysteresis voltage**



**Figure 19. On-state resistance vs  $T_C$** 

**Figure 20. On-state resistance vs  $V_{CC}$** 

**Figure 21. Turn-on voltage slope**

**Figure 22. Turn-off voltage slope**

**Figure 23.  $I_{LIMH}$  vs  $T_C$** 


## 3 Application information

Figure 24. Application schematic



GAPGCFT000119

### 3.1 GND protection network against reverse battery

#### 3.1.1 Solution 1: resistor in the ground line ( $R_{GND}$ only)

This solution can be used with any load type.

The following is an indication on how to dimension the  $R_{GND}$  resistor.

1.  $R_{GND} \leq 600 \text{ mV} / (I_{S(on)max.})$
2.  $R_{GND} \geq (-V_{CC}) / (-I_{GND})$

Where  $-I_{GND}$  is the DC reverse ground pin current and can be found in the absolute maximum rating section of the device datasheet.

Power dissipation in  $R_{GND}$  (when  $V_{CC} < 0 \text{ V}$ : during reverse battery situations) is:

$$P_D = (-V_{CC})^2 / R_{GND}$$

This resistor can be shared among several different HSDs. Please note that the value of this resistor should be calculated with formula (1) where  $I_{S(on)max.}$  becomes the sum of the maximum on-state currents of the different devices.

Please note that if the microprocessor ground is not shared by the device ground then the  $R_{GND}$  produces a shift ( $I_{S(on)max.} \cdot R_{GND}$ ) in the input thresholds and the status output values. This shift varies depending on how many devices are ON in the case of several high side drivers sharing the same  $R_{GND}$ .

If the calculated power dissipation leads to a large resistor or several devices have to share the same resistor, then ST suggests solution 2 is used (see below).

### 3.1.2 Solution 2: diode ( $D_{GND}$ ) in the ground line

A resistor ( $R_{GND} = 4.7 \text{ k}\Omega$ ) should be inserted in parallel to  $D_{GND}$  if the device drives an inductive load.

This small signal diode can be safely shared amongst several different HSDs. Also in this case, the presence of the ground network produces a shift ( $\approx 600 \text{ mV}$ ) in the input threshold and in the status output values, if the microprocessor ground is not common to the device ground. This shift does not vary if more than one HSD shares the same diode/resistor network.

## 3.2 Load dump protection

$D_{ld}$  is necessary (voltage transient suppressor) if the load dump peak voltage exceeds the  $V_{CC}$  maximum DC rating. The same applies if the device is subject to transients on the  $V_{CC}$  line that are greater than the ones shown in the ISO 7637-2 2004 (E) [Table 12](#), [Table 13](#) and [Table 14](#).

## 3.3 MCU I/Os protection

If a ground protection network is used and negative transient is present on the  $V_{CC}$  line, the control pins are pulled negative. ST suggests that a resistor ( $R_{prot}$ ) has to be inserted in line to prevent the microcontroller I/Os pins from latching-up.

The value of these resistors is a compromise between the leakage current of the microcontroller and the current required by the HSD I/Os (Input levels compatibility) with the latch-up limit of microcontroller I/Os.

#### Equation: $R_{prot}$ range calculation

$$-V_{CCpeak}/I_{latchup} \leq R_{prot} \leq (V_{OH\mu C} - V_{IH} - V_{GND}) / I_{IHmax}$$

#### Calculation example:

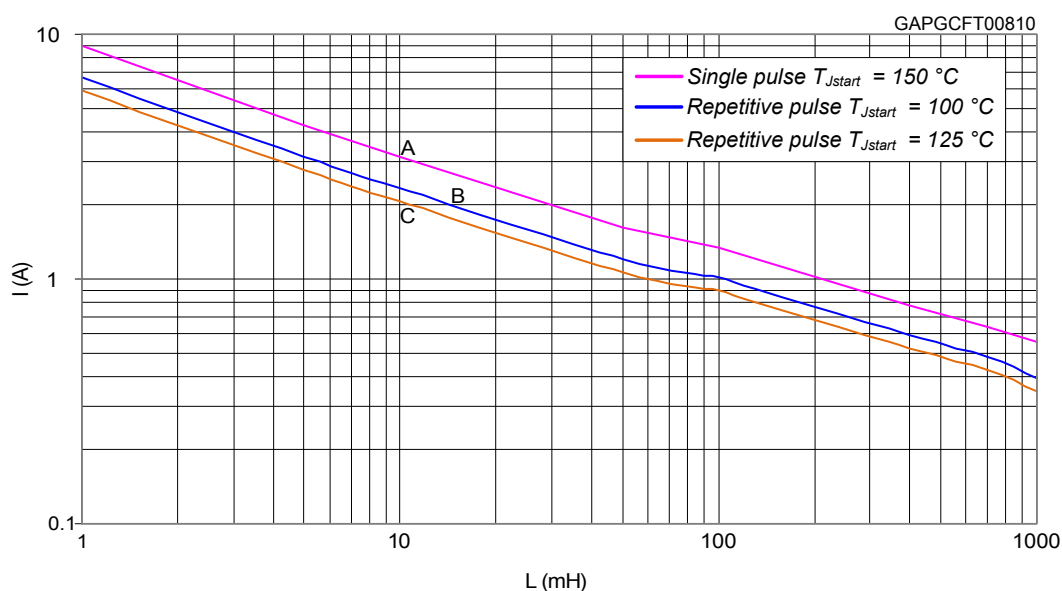
For  $V_{CCpeak} = -600 \text{ V}$  and  $I_{latchup} \geq 20 \text{ mA}$ ;  $V_{OH\mu C} \geq 4.5 \text{ V}$

$30 \text{ k}\Omega \leq R_{prot} \leq 180 \text{ k}\Omega$ .

Recommended value:  $R_{prot} = 60 \text{ k}\Omega$ .

## 4 Maximum demagnetization energy ( $V_{CC} = 24\text{ V}$ )

**Figure 25. Maximum turn off current versus inductance**

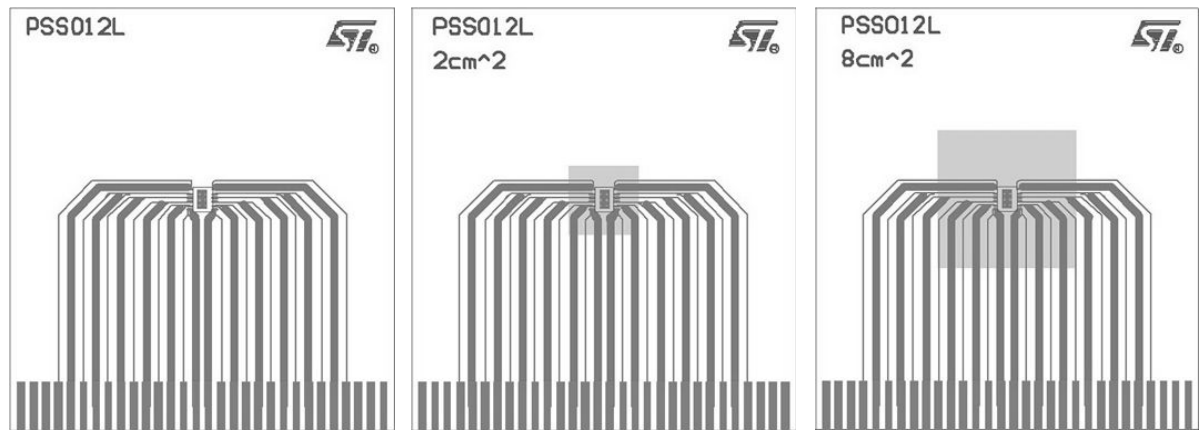


**Note:** Values are generated with  $R_L = 0\ \Omega$ . In case of repetitive pulses,  $T_{Jstart}$  (at the beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves A and B.

## 5 Package and PCB thermal data

### 5.1 PowerSSO-12 thermal data

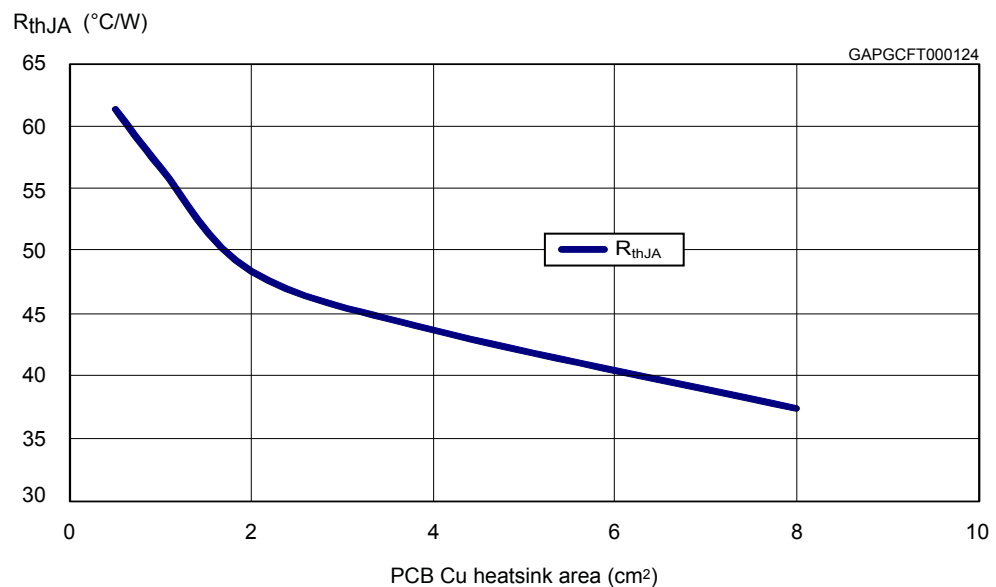
Figure 26. PowerSSO-12 PCB



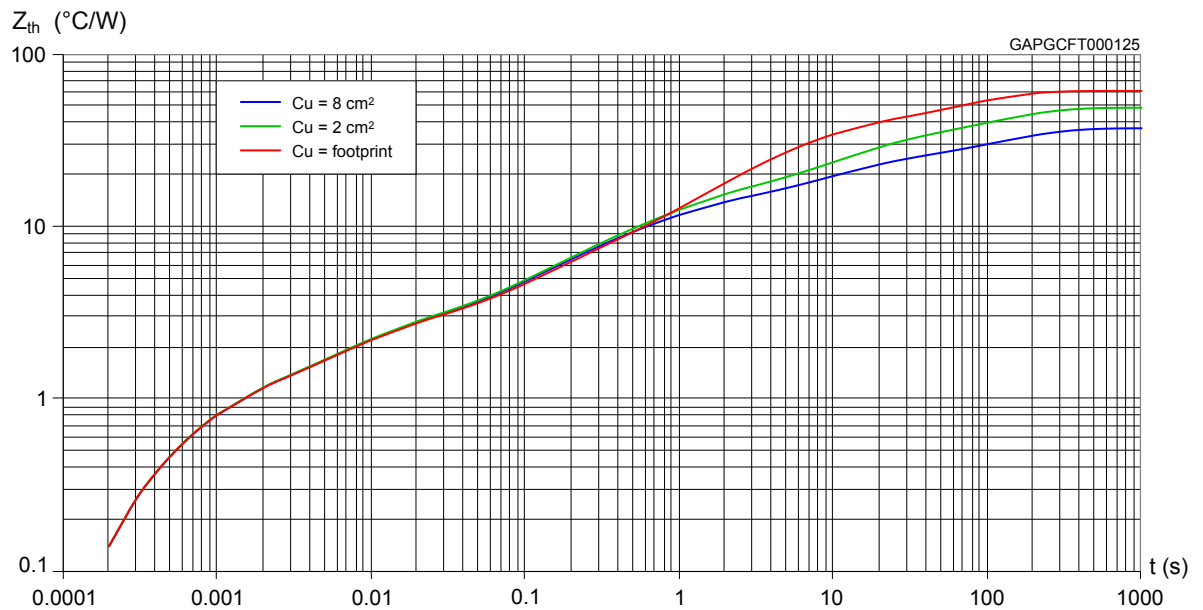
GAPGCFT000120

Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (board finish thickness 1.6 mm  $\pm 10\%$ ; board double layer; board dimension 77 mm x 86 mm; board material FR4; Cu thickness 0.070 mm (front and back side); thermal vias separation 1.2 mm; thermal via diameter 0.3 mm  $\pm 0.08$  mm; Cu thickness on vias 0.025 mm; footprint dimension 4.1 mm x 6.5 mm).

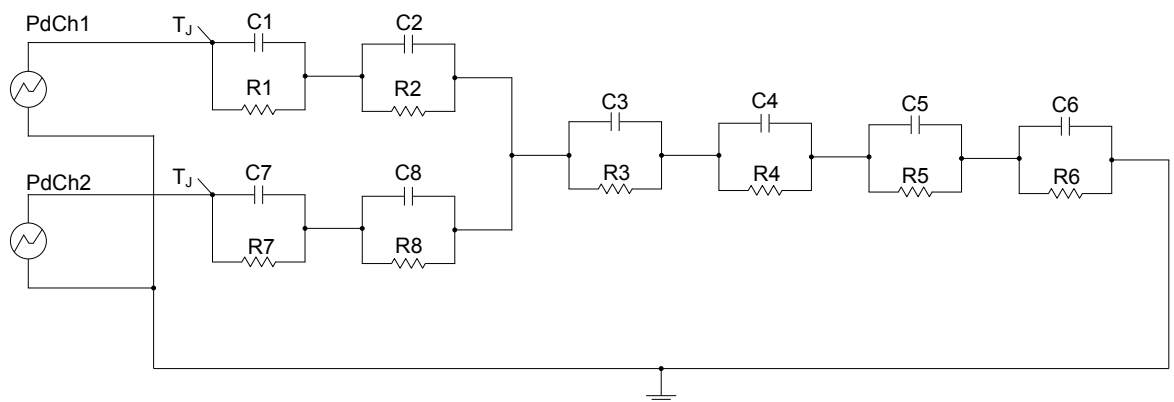
Figure 27.  $R_{thJA}$  vs PCB copper area in open box free air condition (one channel ON)



**Figure 28. PowerSSO-12 thermal impedance junction ambient single pulse (one channel ON)**



**Figure 29. Thermal fitting model of a double channel HSD in PowerSSO-12**



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The fitting model is a simplified thermal tool and is valid for transient evolutions where the embedded protections (power limitation or thermal cycling during thermal shutdown) are not triggered.

**Equation: pulse calculation formula**

$$Z_{th\delta} = R_{th} \cdot \delta + Z_{thtp} (1 - \delta)$$

Where  $\delta = t_p/T$

**Table 15. Thermal parameters**

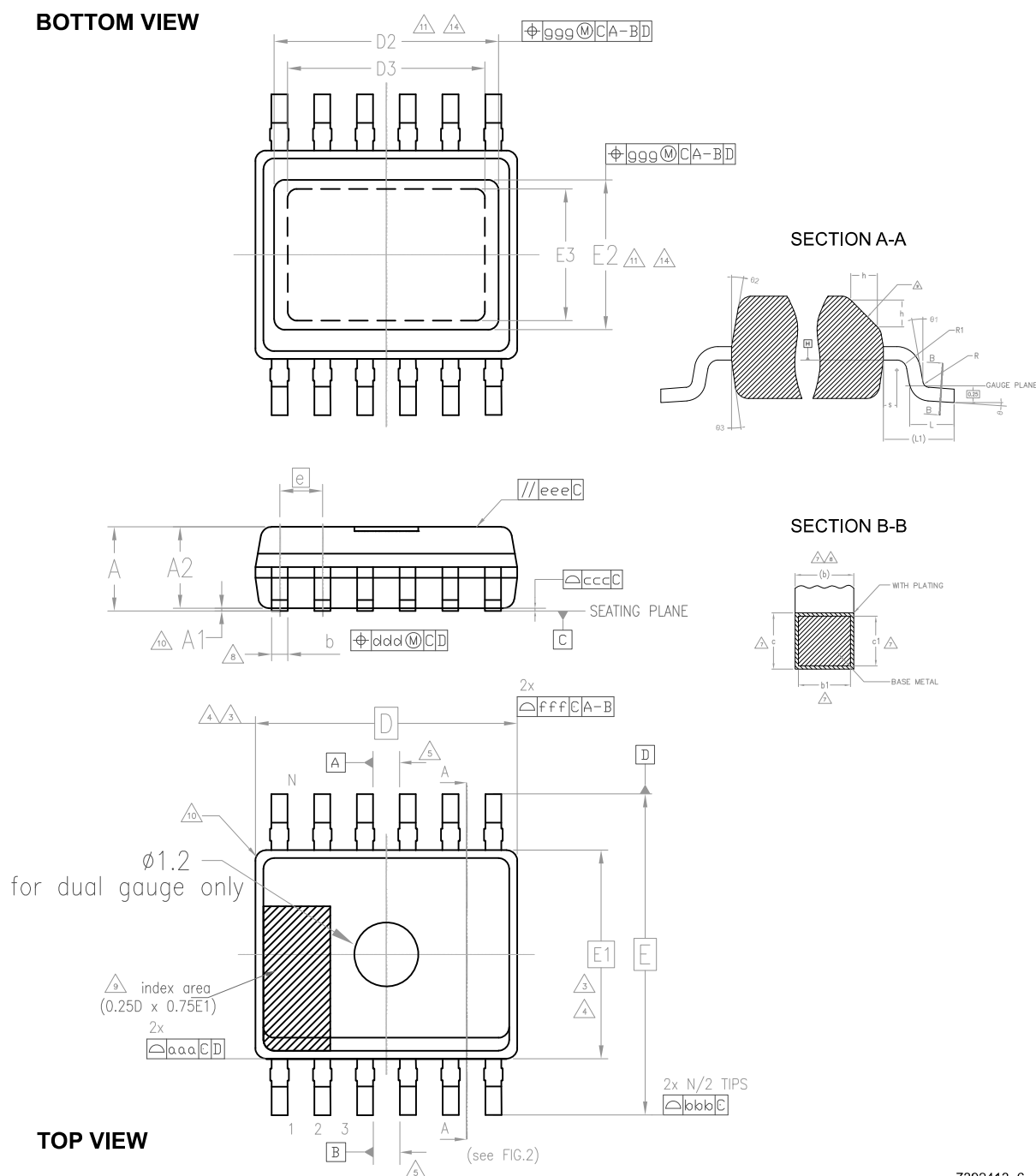
| Area/island (cm <sup>2</sup> ) | Footprint | 2   | 8   |
|--------------------------------|-----------|-----|-----|
| R1 = R7 (°C/W)                 | 0.8       |     |     |
| R2 = R8 (°C/W)                 | 1.5       |     |     |
| R3 (°C/W)                      | 3         |     |     |
| R4 (°C/W)                      | 8         | 8   | 7   |
| R5 (°C/W)                      | 22        | 15  | 10  |
| R6 (°C/W)                      | 26        | 20  | 15  |
| C1 = C7 (W.s/°C)               | 0.0008    |     |     |
| C2 = C8 (W.s/°C)               | 0.005     |     |     |
| C3 (W.s/°C)                    | 0.05      |     |     |
| C4 (W.s/°C)                    | 0.2       | 0.1 | 0.1 |
| C5 (W.s/°C)                    | 0.27      | 0.8 | 1   |
| C6 (W.s/°C)                    | 3         | 6   | 9   |

## 6 Package information

To meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 6.1 PowerSSO-12 package information

**Figure 30. PowerSSO-12 package dimensions**



7392413\_6

**Table 16. PowerSSO-12 mechanical data**

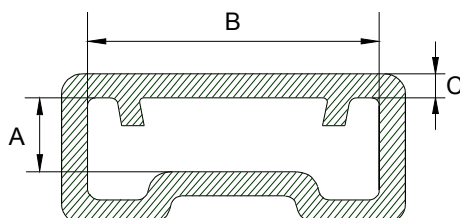
| Symbol     | Millimeters |      |      |
|------------|-------------|------|------|
|            | Min.        | Typ. | Max. |
| $\theta$   | 0°          |      | 8°   |
| $\theta 1$ | 0°          |      |      |
| $\theta 2$ | 5°          |      | 15°  |
| $\theta 3$ | 5°          |      | 15°  |
| A          | 1.25        |      | 1.70 |
| A1         | 0.00        |      | 0.10 |
| A2         | 1.10        |      | 1.60 |
| b          | 0.23        |      | 0.41 |
| b1         | 0.20        | 0.25 | 0.39 |
| c          | 0.19        |      | 0.25 |
| c1         | 0.19        | 0.20 | 0.23 |
| D          | 4.90 BSC    |      |      |
| D2         | 3.60        |      | 4.20 |
| D3         | 2.90        |      |      |
| e          | 0.80 BSC    |      |      |
| E          | 6.00 BSC    |      |      |
| E1         | 3.90 BSC    |      |      |
| E2         | 1.90        |      | 2.50 |
| E3         | 1.20        |      |      |
| h          | 0.25        |      | 0.50 |
| L          | 0.40        |      | 1.27 |
| L1         | 1.00 REF    |      |      |
| N          | 12          |      |      |
| R          | 0.07        |      |      |
| R1         | 0.07        |      |      |
| S          | 0.20        |      |      |

**Table 17. PowerSSO-12 tolerance of form and position**

| Symbol | Millimeters |
|--------|-------------|
| aaa    | 0.10        |
| bbb    | 0.10        |
| ccc    | 0.10        |
| ddd    | 0.08        |
| eee    | 0.10        |
| fff    | 0.10        |
| ggg    | 0.15        |

## 6.2 PowerSSO-12 packing information

**Figure 31. PowerSSO-12 tube shipment (no suffix)**

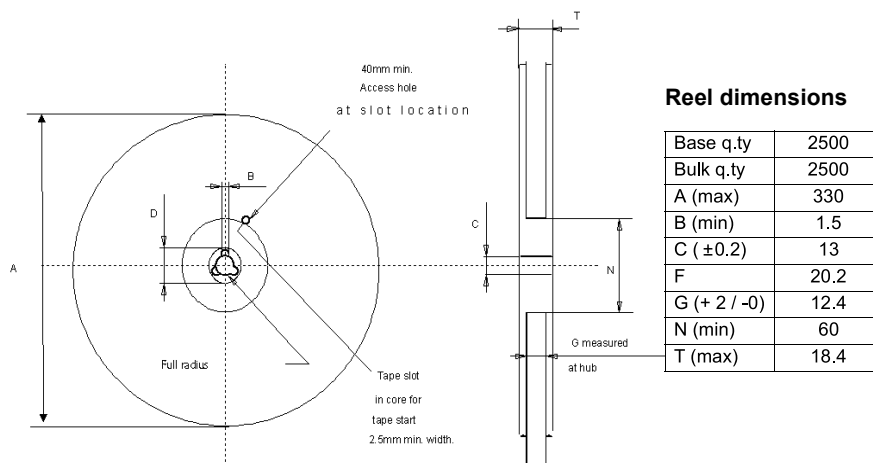


All dimensions are in mm.

|                           |      |
|---------------------------|------|
| Base q.ty                 | 100  |
| Bulk q.ty                 | 2000 |
| Tube length ( $\pm 0.5$ ) | 532  |
| A                         | 1.85 |
| B                         | 6.75 |
| C ( $\pm 0.1$ )           | 0.6  |

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**Figure 32. PowerSSO-12 tape and reel shipment (suffix "TR")**



### Reel dimensions

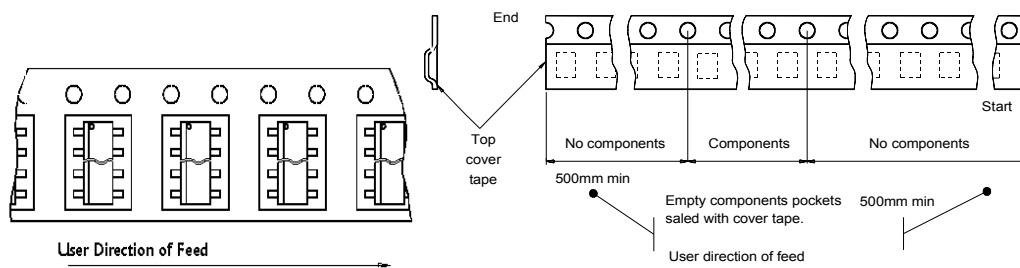
|                 |      |
|-----------------|------|
| Base q.ty       | 2500 |
| Bulk q.ty       | 2500 |
| A (max)         | 330  |
| B (min)         | 1.5  |
| C ( $\pm 0.2$ ) | 13   |
| F               | 20.2 |
| G (+2/-0)       | 12.4 |
| N (min)         | 60   |
| T (max)         | 18.4 |

### Tape dimensions

According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb. 1986

|                   |                  |     |
|-------------------|------------------|-----|
| Tape width        | W                | 12  |
| Tape hole spacing | P0 ( $\pm 0.1$ ) | 4   |
| Component spacing | P                | 8   |
| Hole diameter     | D ( $\pm 0.05$ ) | 1.5 |
| Hole diameter     | D1 (min)         | 1.5 |
| Hole position     | F ( $\pm 0.1$ )  | 5.5 |
| Compartment depth | K (max)          | 4.5 |
| Hole spacing      | P1 ( $\pm 0.1$ ) | 2   |

All dimensions are in mm.



## Revision history

**Table 18. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |
|-------------|----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 08-Mar-2011 | 1        | Initial release.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| 25-Sep-2013 | 2        | Disclaimer updated.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| 22-Mar-2016 | 3        | <i>Table 4: Thermal data:</i><br>– $R_{thj-case}$ : updated value<br>Updated <i>Section 5.1: PowerSSO-12 mechanical data</i> .                                                                                                                                                                                                                                                                                                                                                                                                                |
| 21-Jun-2022 | 4        | Updated <i>PowerSSO-12 cover image</i> and <i>Device summary</i> on cover page.<br>Updated <i>Table 5. Power section</i> .<br>Added notes in <i>Table 12. Electrical transient requirements (part 1)</i><br>Updated <i>Figure 24. Application schematic</i> .<br>Moved <i>Section 3.4: Maximum demagnetization energy (<math>V_{CC} = 24\text{ V}</math>)</i> to <i>Section 4 Maximum demagnetization energy (<math>V_{CC} = 24\text{ V}</math>)</i> .<br>Updated <i>Section 6.1 PowerSSO-12 package information</i> .<br>Minor text changes. |
| 10-Oct-2024 | 5        | Updated <a href="#">Section Device summary</a> in cover page.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |

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